

INTERNATIONAL RECTIFIER 

## 30HFU... SERIES

### SUPER FAST RECTIFIER DIODE 30 Amp 60ns

#### Major ratings and characteristics

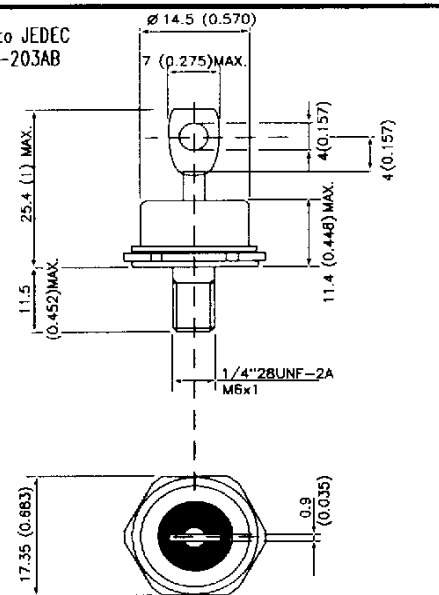
	30HFU	Units
$I_{F(AVG)}$	30	A
$T_c$	91	°C
$I_{RMS}$	47	A
$I_{FSM}$ @ 10ms	475	A
$I_{FSM}$ @ 8.3ms	500	A
$V_{RRM}$	100 to 600	V
$T_J$	-40 to 125	°C

#### Description and Features

- Very low reverse recovery time
- Reduced switching losses
- Soft recovery characteristics
- High surge current capability
- No voltage derating up to 150°C
- Stud cathode and stud anode versions
- Designed for switching applications:  
Free wheeling diode in converters and control circuits  
Rectifier in S.M.P.S.



Conforms to JEDEC  
Outline DO-203AB  
(DO-5)



All dimensions in millimetres (inches)

**ELECTRICAL SPECIFICATIONS**

**Forward Conduction**

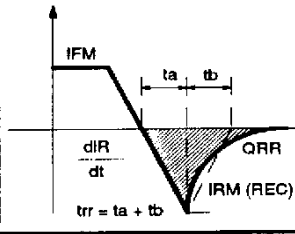
Parameters	Value	Units	Conditions
$I_{F(AV)}$ Maximum average forward current	30	A	180° conduction, half sine cond @ Case temperature = 91°C
	33	A	180° conduction, rect cond @ Case temperature = 91°C
$I_{RMS}$ Maximum RMS current	47	A	
$I_{FSM}$ Maximum peak, one-cycle non-repetitive forward current Initial $T_j = T_j \text{ max.}$	475	A	$t = 10\text{ms}$ No voltage reapplied
	500	A	$t = 8.3\text{ms}$
	400	A	$t = 10\text{ms}$ 100% $V_{RRM}$ reapplied
	420	A	$t = 8.3\text{ms}$
PI Maximum PI for fusing Initial $T_j = T_j \text{ max.}$	1130	A <sup>2</sup> s	$t = 10\text{ms}$ No voltage reapplied
	1030	A <sup>2</sup> s	$t = 8.3\text{ms}$
	800	A <sup>2</sup> s	$t = 10\text{ms}$ 100% $V_{RRM}$ reapplied
	730	A <sup>2</sup> s	$t = 8.3\text{ms}$
$P\sqrt{t}$ Maximum $P\sqrt{t}$ for fusing	11300	A <sup>2</sup> $\sqrt{s}$	$t = 0$ to 10ms, no voltage reapplied
$V_{F(10)}$ Maximum value of threshold voltage	1.08	V	$T_j = 125^\circ\text{C}$
$r_l$ Maximum value of forward slope resistance	6.33	m $\Omega$	$T_j = 125^\circ\text{C}$
$V_{FM}$ Maximum forward voltage drop	1.45	V	$I_M = 30 \text{ Apk}$ $T_j = 25^\circ\text{C}$
	1.25	V	$I_M = 30 \text{ Apk}$ $T_j = 125^\circ\text{C}$

**Thermal and Mechanical Specifications**

$T_j$ Junction temperature range	-40 to 125	°C	
$T_{stg}$ Storage temperature range	-40 to 150	°C	
$R_{thJC}$ Maximum thermal resistance junction to case	0.60	K/W	DC operation per junction
$R_{thCS}$ Maximum thermal resistance, case to heatsink	0.25	K/W	Mounting surface, smooth and greased
T Mounting torque, base to heatsink $\pm 10\%$	2.5	Nm	A mounting compound is recommended and the torque should be rechecked after a period of about 3 hours to allow for the spread of the compound
wl Approximate weight	25	g	

**Recovery Characteristics**

Parameters	Typ.	Max.	Units	Conditions
$t_{rr}$ Recovery time	60	80	ns	$T_j = 25^\circ\text{C}$ $I_F = 1\text{A}$ , $diF/dt = -100 \text{ A}/\mu\text{s}$ , $V_r = -30\text{V}$
$Q_{rr}$ Recovered charge	200	250	nC	$T_j = 25^\circ\text{C}$ $I_F = 1\text{A}$ , $diF/dt = -100 \text{ A}/\mu\text{s}$ , $V_r = -30\text{V}$



**Voltage ratings ( $T_j = T_j \text{ max.}$ )**

Type number	$V_{RRM}$ , maximum repetitive peak reverse voltage		$V_{RSM}$ , maximum non-repetitive peak reverse voltage		$I_{RRM} \text{ Max}$	$I_{RRM} \text{ Max}$	$I_{RRM}$
					@ 100°C	@ 150°C	Typ. @ 25°C
	V		V		mA	mA	$\mu\text{A}$
30HFU(R)-100	100		110		2.5	10	35
30HFU(R)-200	200		220		2.5	10	35
30HFU(R)-300	300		330		2.5	10	35
30HFU(R)-400	400		440		2.5	10	35
30HFU(R)-500	500		550		2.5	15	35
30HFU(R)-600	600		660		2.5	15	35

**ΔR Conduction (per junction)**

(The following table shows the increment of thermal resistance  $R_{th\ J-C}$  when devices operate at different conduction angles than DC.)

Conduction angle	Sinusoidal conduction	Rectangular conduction	Units	Conditions
180°	0.09	0.08	K/W	
120°	0.12	0.14	K/W	
90°	0.16	0.18	K/W	
60°	0.23	0.24	K/W	
30°	0.35	0.36	K/W	

Fig.1 - Maximum Forward Energy Loss Per Pulse Characteristics

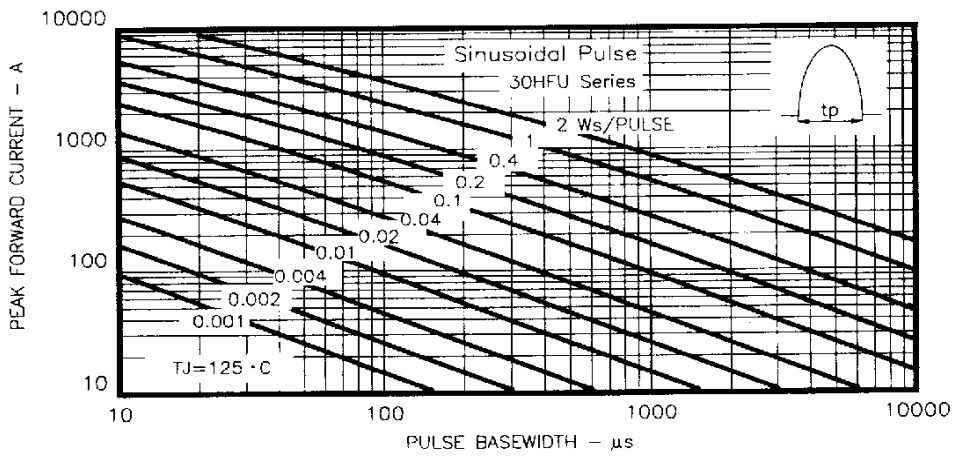
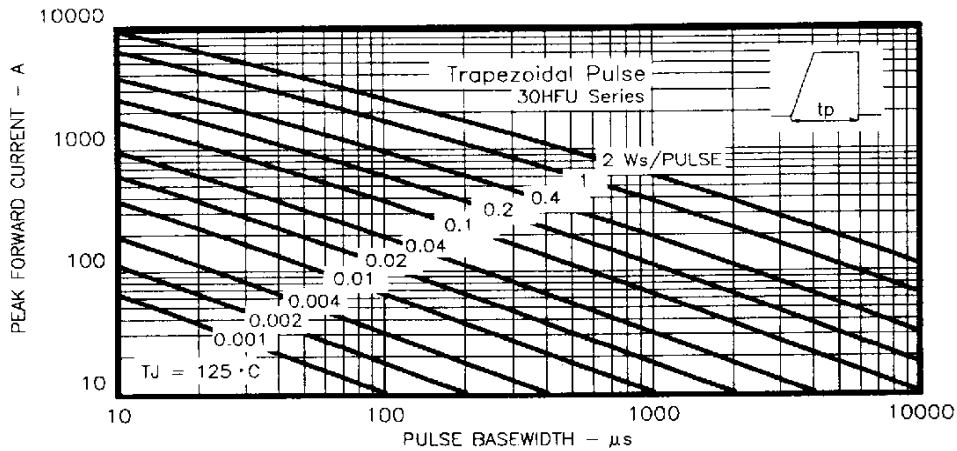
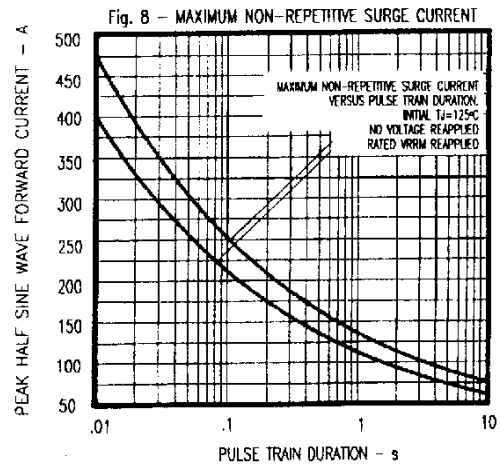
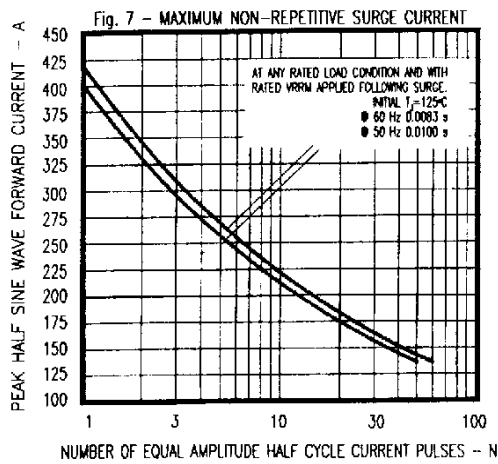
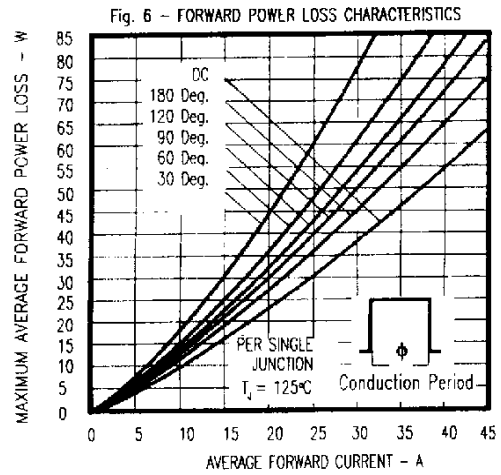
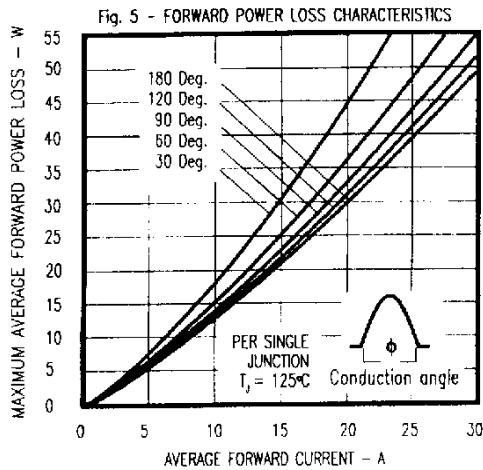
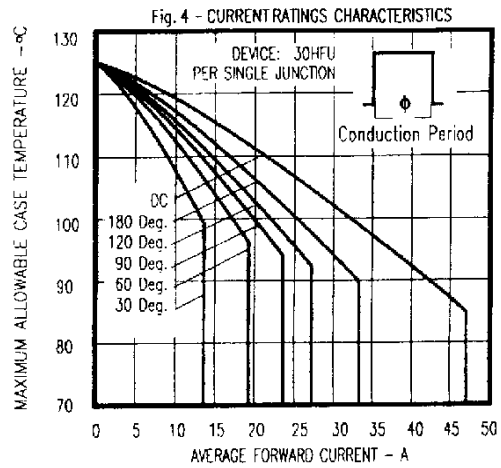
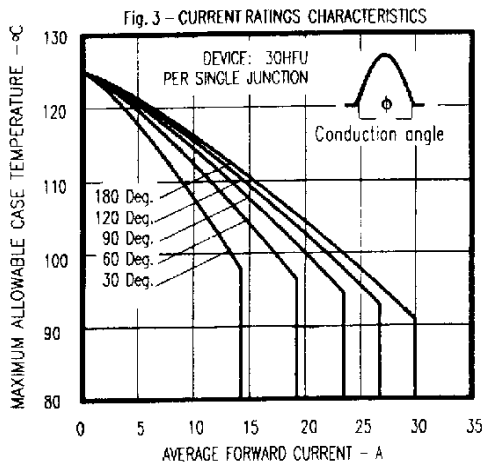
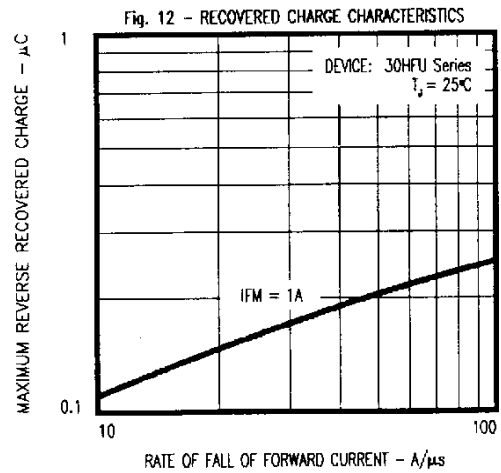
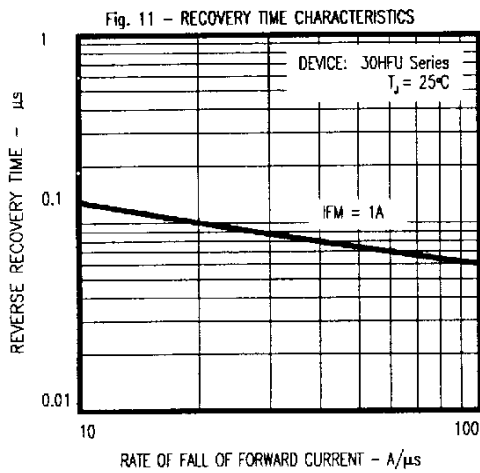
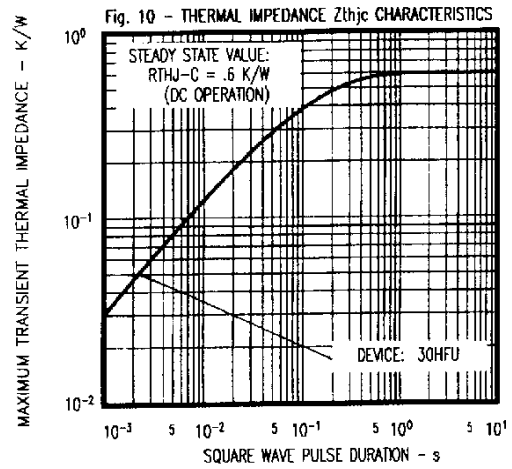
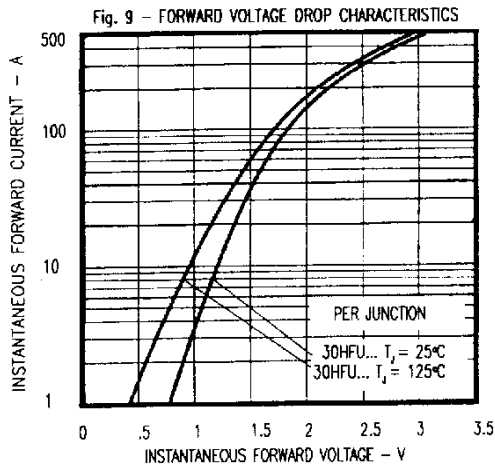


Fig.2 - Maximum Forward Energy Loss Per Pulse Characteristics







# INTERNATIONAL RECTIFIER



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In the interest of product improvement INTERNATIONAL RECTIFIER reserves the right to change specifications at any time without notice 9/88